



DMN1002UCA6

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{SSS}	Rss(on) Typ	Is мах Та = +25°С
12V	2.36mΩ @ V _{GS} = 3.8V	24.4A

Description

This new generation MOSFET is designed to minimize the on-state resistance (Rss(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Battery Management
- Load Switch
- Battery Protection

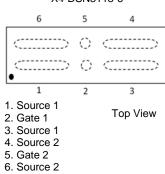
Features

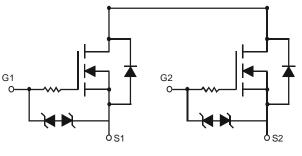
- CSP with Footprint 3.05mm × 1.77mm
- Height = 0.11mm for Low Profile
- ESD Protection of Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: X4-DSN3118-6
- Terminal Connections: See Diagram Below
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0012 grams (Approximate)







Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN1002UCA6-7	X4-DSN3118-6	3000/Tape & Reel

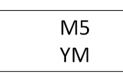
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Notes:

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



M5 = Product Type Marking Code

YM = Date Code Marking

Y or \overline{Y} = Year (ex: G = 2019)

M or \overline{M} = Month (ex: 9 = September)

Date Code Key

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Year	2017	20	18	2019	2020	20	21	2022	2023	20	24	2025
Code	E	ŀ	=	G	Н		I	J	K		L	М
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

X4-DSN3118-6

Lead-free.



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Source-Source Voltage	Vsss	12	V		
Gate-Source Voltage	Vgss	±8	V		
Continuous Source Current (Note 5) V_{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	ls	24.4 19.6	А
Continuous Source Current (Note 5) $V_{GS} = 2.5V$	ls	16.4 13.1	А		
Pulsed Source Current (Note 6)	lsм	100	A		

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7)	PD	1.10	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 7)	R _{0JA}	114.1	°C/W
Power Dissipation (Note 5)	PD	2.47	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	R _{0JA}	50.7	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	٥°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

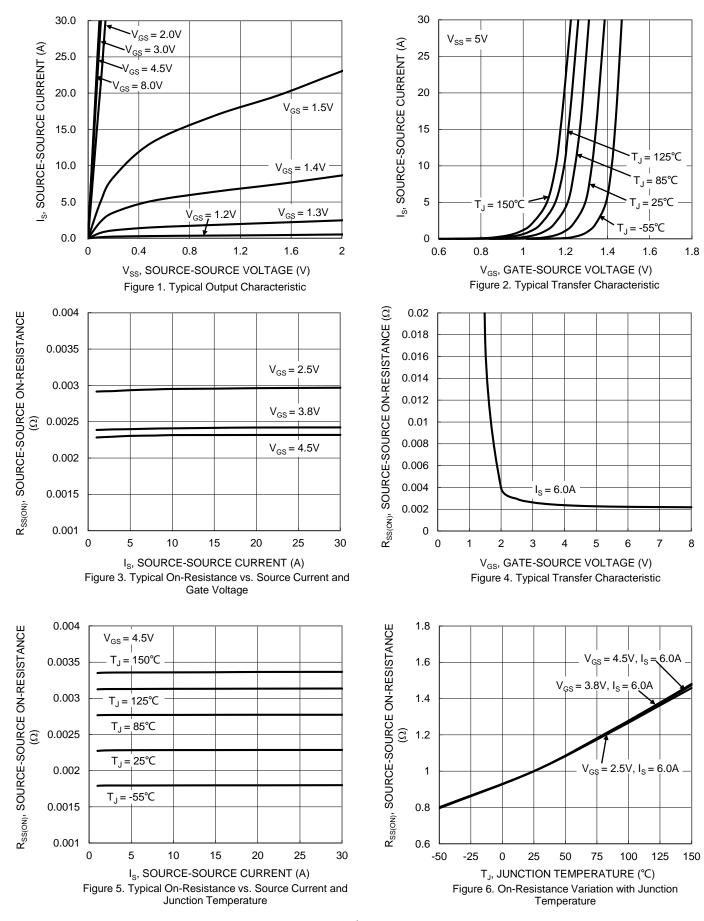
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 8)								
Source-Source Breakdown Voltage	BVsss	12	_	—	V	$V_{GS} = 0V$, $I_S = 1mA$		
Zero Gate Voltage Drain Current TJ = +25°C	lsss	_	_	1	μA	Vss = 9.6V, Vgs = 0V		
Coto Source Leokage	l	_	_	±10	μA	$V_{GS} = \pm 8V, V_{SS} = 0V$		
Gate-Source Leakage	lgss	_	_	±1.0	μA	$V_{GS} = \pm 5V$, $V_{SS} = 0V$		
ON CHARACTERISTICS (Note 8)								
Gate Threshold Voltage	Vgs(th)	0.35	0.8	1.4	V	Vss = 10V, Is = 1.41mA		
		1.5	2.27	2.75		VGS = 4.5V, IS = 6A		
Static Source-Source On-Resistance	Descent	1.6	2.36	2.85		V _{GS} = 3.8V, I _S = 6A		
Static Source-Source On-Resistance	Rss(on)	1.7	2.54	3.95	mΩ	VGS = 3.1V, IS = 6A		
		1.9	2.9	6.1		Vgs = 2.5V, Is = 6A		
Diode Forward Voltage	Vss		0.69	1.2	V	$V_{GS} = 0V$, $I_S = 6A$		
DYNAMIC CHARACTERISTICS (Note 9)								
Input Capacitance	Ciss	_	3062	4593				
Output Capacitance	Coss	—	758	1137	pF	$V_{SS} = 10V, V_{GS} = 0V,$ f = 1kHz		
Reverse Transfer Capacitance	Crss	_	198	297				
Total Gate Charge	Qg		45.7	68.6				
Gate-Source Charge	Qgs	_	8.3	12.5	-0	$V_{SS} = 8V, V_{GS} = 4V,$		
Gate-Drain Charge	Q _{gd}		16.0	24.0	nC	Is = 6A		
Gate Charge at VTH	Qg(th)		4.5	6.8				
Turn-On Delay Time	t _{D(ON)}		1005	1508				
Turn-On Rise Time	tR		2186	3279		$V_{SS} = 8V, V_{GS} = 4V,$		
Turn-Off Delay Time	tD(OFF)	—	2643	3965	ns	Is = 6A		
Turn-Off Fall Time	tF	_	4193	6290	1			

 Device mounted on FR-4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.
Repetitive rating, pulse width limited by junction temperature.
Device mounted on FR-4 PCB with minimum recommended pad layout, single sided. Notes:

8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to production testing.

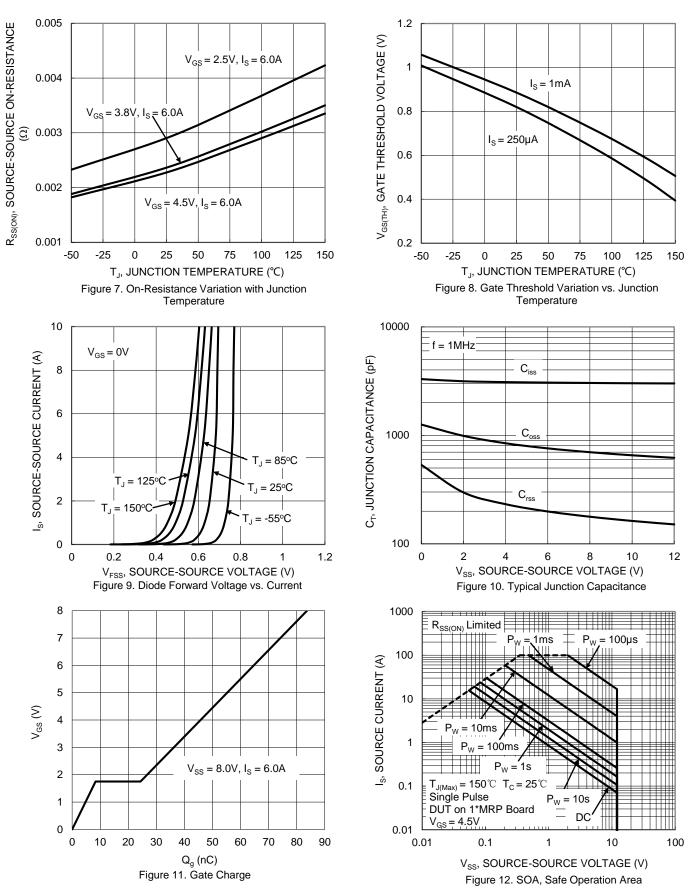


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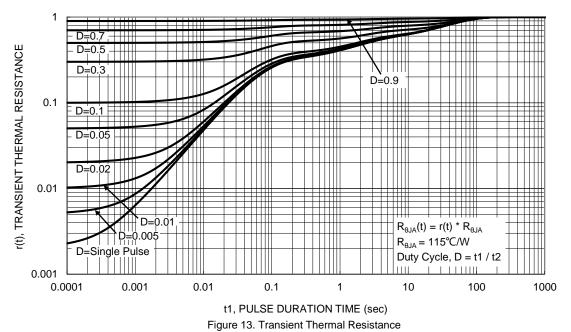




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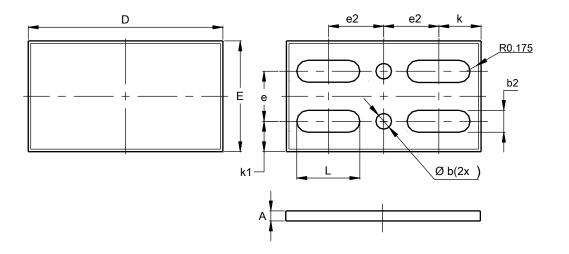




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X4-DSN3118-6

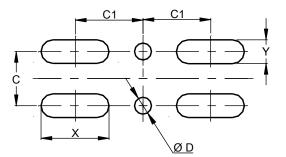


X4-DSN3118-6						
Dim	Min	Max	Тур			
Α	0.09	0.16	0.11			
b			0.25			
b2	0.32	0.38	0.35			
D	3.00	3.10	3.05			
E	1.72	1.82	1.77			
е			0.800			
e2			0.878			
k			0.648			
k1			0.485			
L	0.975	1.035	1.005			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X4-DSN3118-6



Dimensions	Value (in mm)
С	0.800
C1	0.878
D	0.250
X	1.005
Y	0.350



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